

INFORMATION DISCLOSURE CITATION IN AN APPLICATION (Use several sheets if necessary)				Initials Examiner (Spouse) HALO-01-0140	Initials Attorney 10/697,520	
				Applicant Seiki Ogura et al.		
				Filing Date 10/30/03	Group Art Unit 100	
U. S. PATENT DOCUMENTS						
EXAMINER INITIALS IA	DOCUMENT NUMBER 4943943	DATE 7/24/90	NAME Hayashi et al.	CLASS 365	SUBCLASS 185	FILED DATE IF APPROPRIATE 7/24/84
IA	5768192	6/16/98	Eitan	365	185.24	7/23/96
FOREIGN PATENT DOCUMENTS						
	DOCUMENT NUMBER JP 11-22940	DATE 12/5/97	COUNTRY Japan	CLASS H01L	SUBCLASS 27/115	TRANSLATED <input checked="" type="checkbox"/> YES <input type="checkbox"/> NO
IA	JP 00-31435	7/8/98	Japan	H01L	27/115	
OTHER DOCUMENTS (Including Author, Title, Date, Portion or Pages, Etc.)						
IA	F.Masuoka et al., "A New NAND Cell for Ultra High Density 5V-Only EEPROMs," May 1988, Proc. 1988 Symp. on VLSI Tech., IV-5, pp. 33-34.					
EXAMINER Ogura				DATE CONSIDERED 7/4/04		

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP § 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to the applicant.